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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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TIP42 TIP42A TIP42B TIP42C

# PNP SILICON POWER TRANSISTOR



www.centralsemi.com

## **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR TIP42 SERIES types are PNP Epitaxial-Base Silicon Power Transistors designed for power amplifier and high speed switching applications.

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T <sub>C</sub> =25°C) Collector-Base Voltage	SYMBOL V <sub>CBO</sub>	TIP42 40	<b>TIP42A</b> 60	TIP42B 80	<b>TIP42C</b> 100	UNITS V
Collector-Emitter Voltage	$V_{CEO}$	40	60	80	100	V
Emitter-Base Voltage	$V_{EBO}$		5	.0		V
Continuous Collector Current	IC		6	.0		Α
Peak Collector Current	I <sub>CM</sub>		1	0		Α
Continuous Base Current	$I_{B}$		2	.0		Α
Power Dissipation	$P_{D}$		6	5		W
Power Dissipation (T <sub>A</sub> =25°C)	$P_{D}$		2	.0		W
Operating and Storage Junction Temperature	T I, Teta		-65 to	+150		°C

Operating and Storage Junction Temperature		$T_J$ , $T_{stg}$	-65 to +150		°C
ELECTRICAL	<b>CHARACTERISTICS</b> : (T <sub>C</sub> =25°C u	ınless otherwise n	oted)		
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
ICEO	V <sub>CE</sub> =30V (TIP42, TIP42A)			0.7	mA
ICEO	V <sub>CE</sub> =60V (TIP42B, TIP42C)			0.7	mA
ICES	V <sub>CE</sub> =Rated V <sub>CEO</sub>			0.4	mA
I <sub>EBO</sub>	V <sub>EB</sub> =5.0V			1.0	mA
$BV_{CEO}$	I <sub>C</sub> =30mA (TIP42)	40			V
BVCEO	I <sub>C</sub> =30mA (TIP42A)	60			V
$BV_{CEO}$	I <sub>C</sub> =30mA (TIP42B)	80			V
$BV_{CEO}$	I <sub>C</sub> =30mA (TIP42C)	100			V
V <sub>CE</sub> (SAT)	I <sub>C</sub> =6.0A, I <sub>B</sub> =0.6A			1.5	V
V <sub>BE(ON)</sub>	$V_{CE}$ =4.0V, $I_{C}$ =6.0A			2.0	V
h <sub>FE</sub>	$V_{CE}$ =4.0V, $I_{C}$ =0.3A	30			
hFE	$V_{CE}$ =4.0V, $I_{C}$ =3.0A	15		75	
h <sub>fe</sub>	$V_{CE}$ =10V, $I_{C}$ =0.5A, f=1.0kHz	20			
$f_{T}$	$V_{CE}$ =10V, $I_{C}$ =0.5A, f=1.0MHz	3.0			MHz
t <sub>on</sub>	$I_C$ =6.0A, $I_{B1}$ = $I_{B2}$ =0.6A, $R_L$ =5.0 $\Omega$		0.4		μs
toff	$I_C$ =6.0A, $I_{B1}$ = $I_{B2}$ =0.6A, $R_L$ =5.0 $\Omega$		0.7		μs

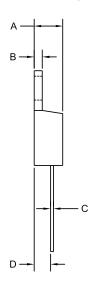
R2 (22-July 2014)

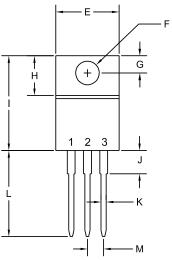
TIP42 TIP42A TIP42B TIP42C

# PNP SILICON POWER TRANSISTOR



## **TO-220 CASE - MECHANICAL OUTLINE**





R2

## LEAD CODE:

- 1) Base
- 2) Collector
- 3) Emitter
- Tab) Collector

## MARKING:

FULL PART NUMBER

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0.170	0.190	4.31	4.82			
В	0.045	0.055	1.15	1.39			
С	0.013	0.026	0.33	0.65			
D	0.083	0.107	2.10	2.72			
E	0.394	0.417	10.01	10.60			
F (DIA)	0.140	0.157	3.55	4.00			
G	0.100	0.118	2.54	3.00			
Н	0.230	0.270	5.85	6.85			
	0.560	0.625	14.23	15.87			
J	-	0.250	-	6.35			
K	0.025	0.038	0.64	0.96			
L	0.500	0.579	12.70	14.70			
M	0.090	0.110	2.29	2.79			

TO-220 (REV: R2)

#### **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- · Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

#### REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

#### **CONTACT US**

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